

■ Features

- Wide Bandgap SiC MOSFET Technology.
- Low On-Resistance with High Blocking Voltage.
- Low Capacitances with High-Speed Switching.
- Low Reverse Recovery (Qrr).
- Easy to Parallel and Simple to Drive.
- Robust against Parasitic Turn on Even 0V Turn off Gate Voltage.

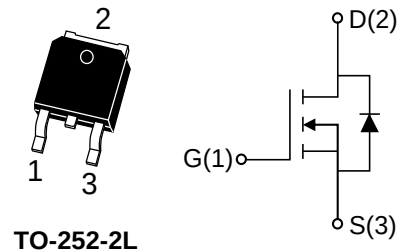
Parameter	Value	Unit
V_{DS}	650	V
$R_{DS(on)}_{typ@VGS=18V}$	350	mΩ
$I_{D@VGS=18V,TC=25^{\circ}C}$	7.7	A

■ Benefits

- Reduced Switching Losses.
- Increased System Switching Frequency.
- Increased Power Density.
- Reduction of Heat Sink Requirements.
- Reduced EMI.

■ Application

- Switch Mode Power Supplies.
- High Voltage DC/DC Converters.
- Battery Chargers.
- Motor Drives.
- Pulsed Power Applications.



Maximum ratings($T_j=25^{\circ}C$, Unless otherwise specified)

Parameter	Symbol	Test Condition	Value	Unit
Drain to Source Voltage	$V_{DS,max}$	$V_{GS}=0V, I_D=500\mu A$	650	V
Gate to Source Voltage	$V_{GS,max}$	Absolute Maximum Values	-10/+22	V
Recommended Operation Voltage of Gate to Source	$V_{GS,op}$	Recommended Operational Values	0/+15...+18	V
Continuous Drain Current	I_D	$V_{GS}=15V, TC=25^{\circ}C$	7	A
		$V_{GS}=15V, TC=100^{\circ}C$	5	A
Continuous Drain Current		$V_{GS}=18V, TC=25^{\circ}C$	7.7	A
		$V_{GS}=18V, TC=100^{\circ}C$	5.4	A
Pulsed Drain Current	$I_{D(pulsed)}$	Pulse with T_p limited by T_{jmax}	12	A
Avalanche energy, Single pulse	E_{AS}	$V_{DD}=100V, L=10mH, T_j(start)=25^{\circ}C$	5	mJ
Power Dissipation	P_{tot}	$TC=25^{\circ}C, T_j=175^{\circ}C$	35	W
Operating and Storage Temperature	T_j, T_{stg}	—	-55 to +175	$^{\circ}C$
Solder Temperature, 1.6mm from case for 10s	T_L	—	260	$^{\circ}C$



Thermal Characteristics

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Thermal Resistance from Junction to Case	$R_{\theta JC}$	—	4.3	—	$^{\circ}\text{C/W}$

Electrical Characteristics

Static Characteristics

Parameter	Symbol	Test Condition	Value			Unit
			Min	Typ	Max	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=3.5\text{mA}, T_j=25^{\circ}\text{C}$	3	3.8	4.8	V
		$V_{GS}=V_{DS}, I_D=3.5\text{mA}, T_j=175^{\circ}\text{C}$	—	2.7	—	V
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0\text{V}, I_D=500\mu\text{A}$	650	—	—	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{GS}=0\text{V}, V_{DS}=650\text{V}, T_j=25^{\circ}\text{C}$	—	—	50	μA
Gate to Source Leakage Current	I_{GSS+}	$V_{GS}=22\text{V}, V_{DS}=0\text{V}, T_j=25^{\circ}\text{C}$	—	—	250	nA
	I_{GSS-}	$V_{GS}=-10\text{V}, V_{DS}=0\text{V}, T_j=25^{\circ}\text{C}$	—	—	-250	nA
Drain to Source on Resistance	$R_{DS(on)}$	$V_{GS}=15\text{V}, I_D=4\text{A}, T_j=25^{\circ}\text{C}$	—	480	650	m Ω
		$V_{GS}=15\text{V}, I_D=4\text{A}, T_j=175^{\circ}\text{C}$	—	509	—	m Ω
		$V_{GS}=18\text{V}, I_D=4\text{A}, T_j=25^{\circ}\text{C}$	—	350	500	m Ω
		$V_{GS}=18\text{V}, I_D=4\text{A}, T_j=175^{\circ}\text{C}$	—	430	—	m Ω
Transconductance	g_{fs}	$V_{DS}=20\text{V}, I_{DS}=4\text{A}, T_j=25^{\circ}\text{C}$	—	2.6	—	S



Electrical Characteristics

Dynamic Characteristics

Parameter	Symbol	Test Condition	Value			Unit
			Min	Typ	Max	
Input Capacitance	C_{iss}	VGS=0V, VDS=400V, f=1MHz, Tj=25°C	—	149	—	pF
Output Capacitance	C_{oss}		—	11	—	pF
Reverse Transfer Capacitance	C_{rss}		—	0.8	—	pF
Gate-Source Charge	Q_{gs}	VGS=0/15V, VDS=400V, ID=4A, Tj=25°C	—	3	—	nC
Gate-Drain Charge	Q_{gd}		—	1.1	—	nC
Total Gate Charge	Q_g		—	6.7	—	nC
Gate Resistance	R_g	VAC=25mV, f=1MHz	—	35	—	Ω

Switching Characteristics

Parameter	Symbol	Test Condition	Value			Unit
			Min	Typ	Max	
Turn-On Delay Time	$t_{d(on)}$	VGS=0/15V, VDD=400V, ID=4A, Rg=10Ω, L=600uH, Tj=25°C	—	16.1	—	ns
Rise Time	t_r		—	13.9	—	ns
Turn-Off Delay Time	$t_{d(off)}$		—	13.3	—	ns
Fall Time	t_f		—	13.7	—	ns
Turn-On Switching Energy	E_{on}	VGS=0/15V, VDD=400V, ID=4A, Rg=10Ω, L=600uH, Tj=25°C	—	41.2	—	μJ
Turn-Off Switching Energy	E_{off}		—	3.08	—	μJ

Reverse Diode Characteristics

Parameter	Symbol	Test Condition	Value			Unit
			Min	Typ	Max	
Diode Forward Voltage	V_{SD}	VGS=0V, ISD=2A, Tj=25°C	—	4.8	—	V
		VGS=0V, ISD=2A, Tj=175°C	—	3.3	—	V
Continuous Diode Forward Current	I_S	VGS=0V, Tj=25°C	—	6	—	A
Reverse Recovery Time	t_{rr}	VGS=0V, ISD=4A, VR=400V, -di/dt=1100A/us, Tj=25°C	—	7.9	—	ns
Reverse Recovery Charge	Q_{rr}		—	20	—	nC
Peak Reverse Recovery Current	I_{rrm}		—	4.2	—	A



Typical Performance

Fig1. Output Characteristics $T_j = -55^\circ\text{C}$

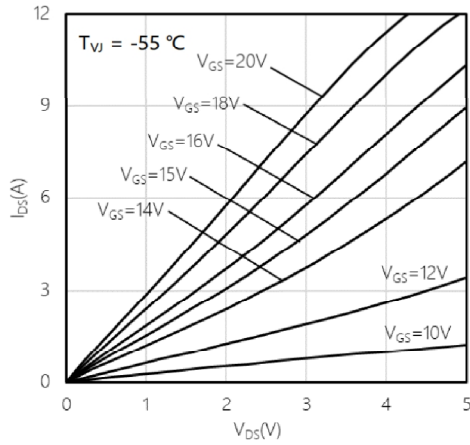


Fig2. Output Characteristics $T_j = 25^\circ\text{C}$

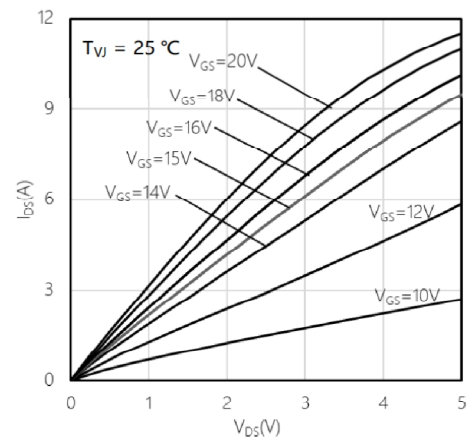


Fig3. Output Characteristics $T_j = 175^\circ\text{C}$

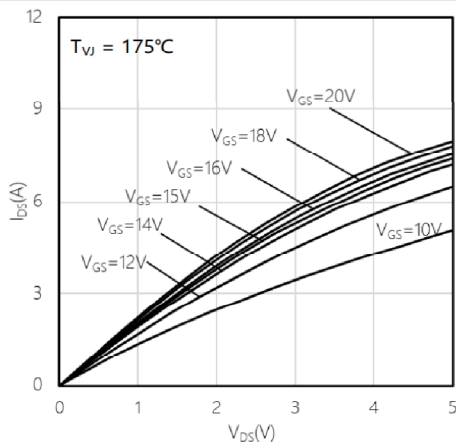


Fig4. On-Resistance vs. Temperature For Various Gate Voltages

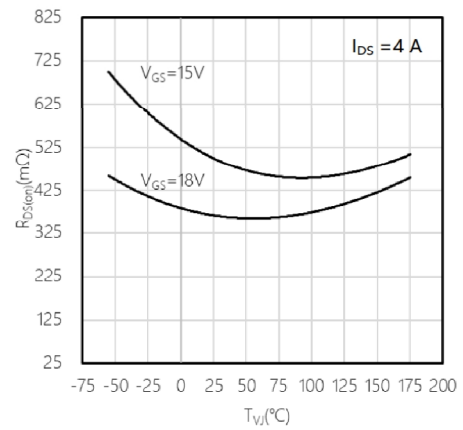


Fig5. On-Resistance vs. Drain Current For Various Temperatures

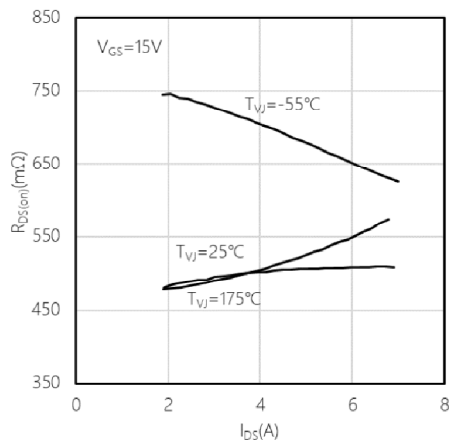
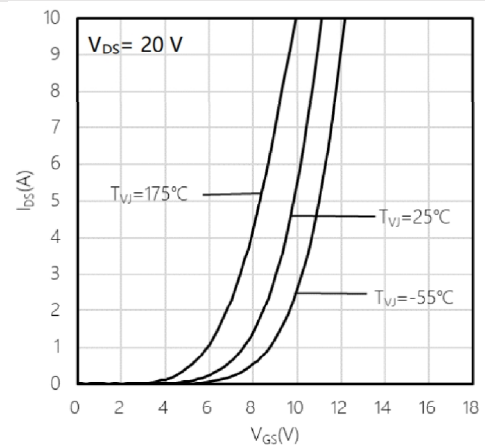


Fig6. Transfer Characteristic for Various Junction Temperature



Typical Performance

Fig7. Typical Reverse Drain Current vs. Reverse Drain Voltage at Different VGS Tj=-55°C

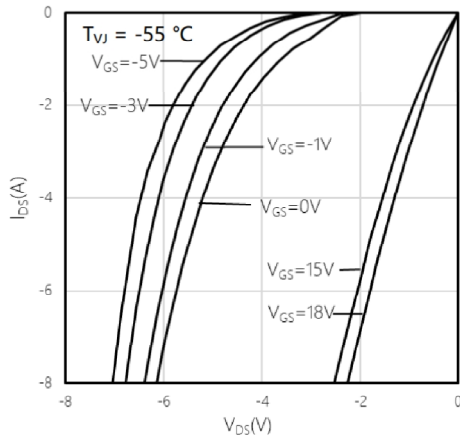


Fig8. Typical Reverse Drain Current vs. Reverse Drain Voltage at Different VGS Tj=25°C

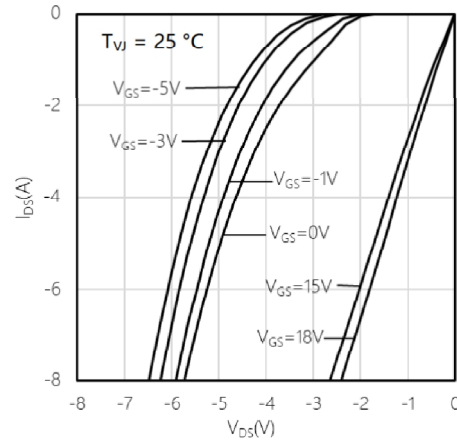


Fig9. Typical Reverse Drain Current vs. Reverse Drain Voltage at Different VGS Tj=175°C

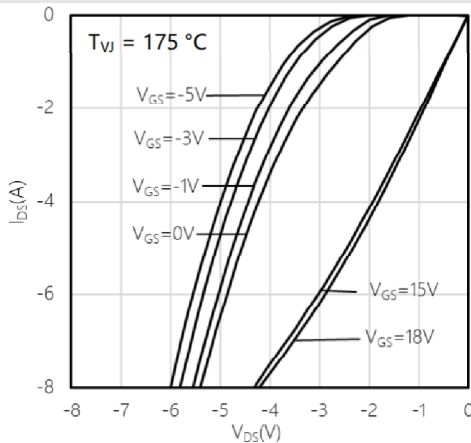


Fig10. Threshold Voltage vs. Temperature

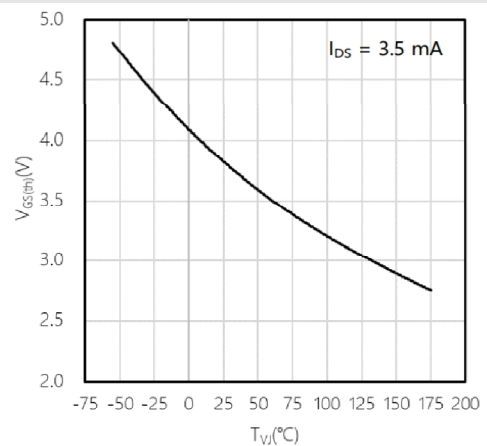


Fig11. Gate Charge Characteristics

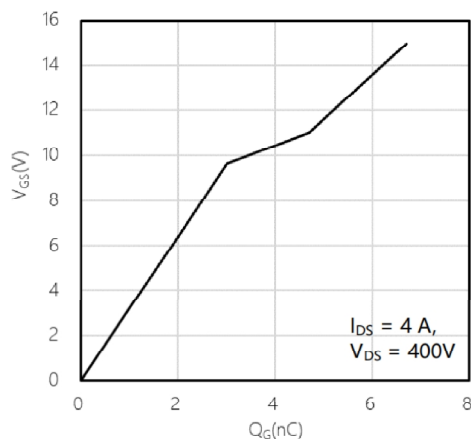
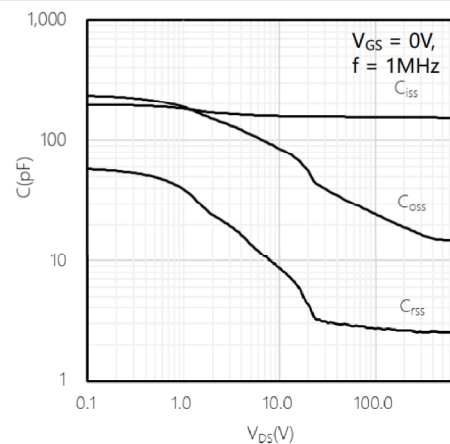


Fig12. Capacitances vs. Drain-Source Voltage(0-200V)



Typical Performance

Fig13. Clamped Inductive Switching Energy vs. Drain Current

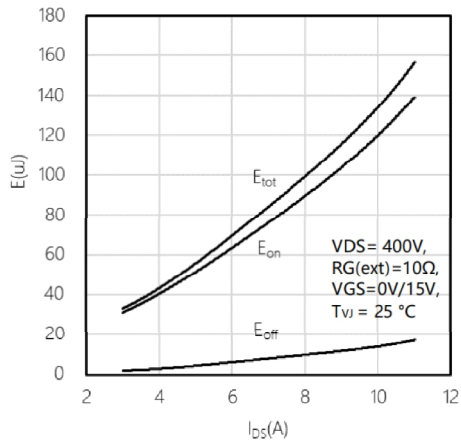


Fig14. Clamped Inductive Switching Energy vs. R_g at $T_j=25^\circ C$

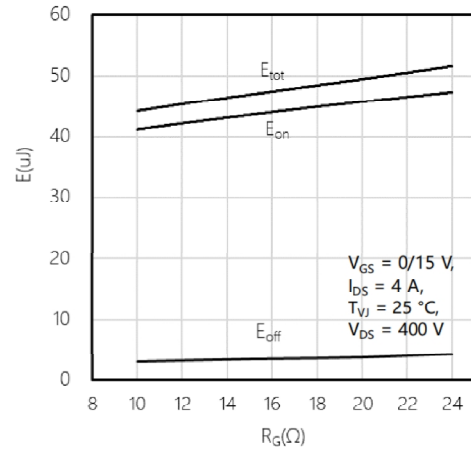


Fig15. Clamped inductive switching energy vs. temperature at $T_j=25^\circ C$

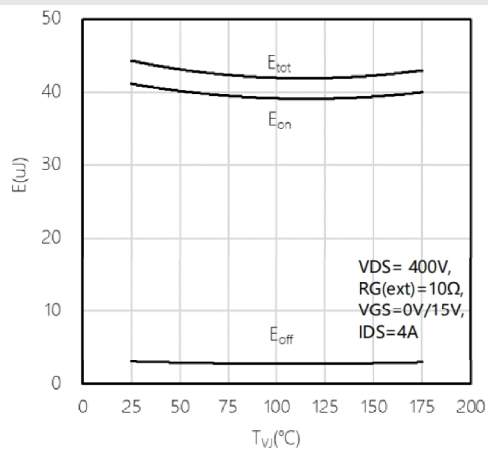


Fig16. Maximum Power Dissipation Derating vs. Case Temperature

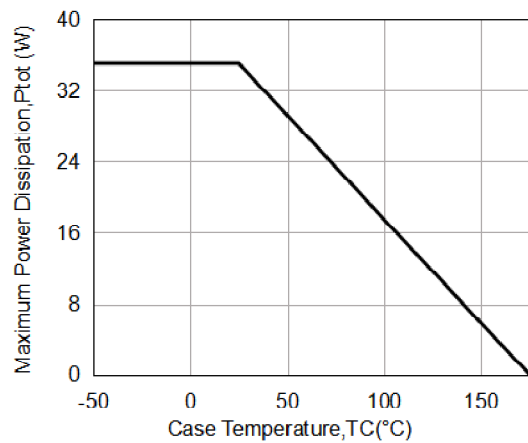
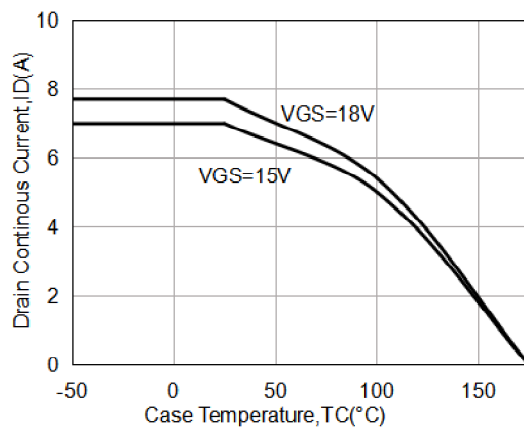
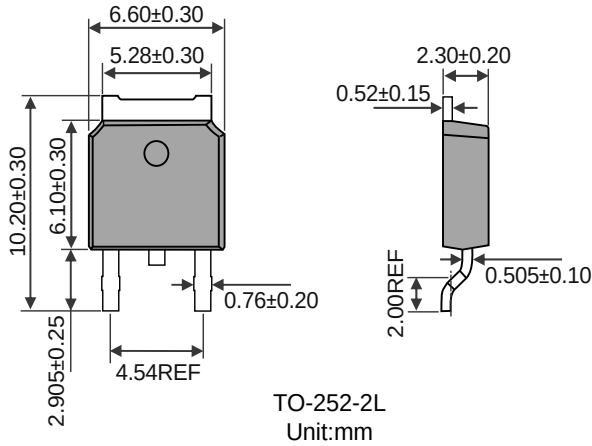


Fig17. Continuous Drain Current Derating vs. Case Temperature

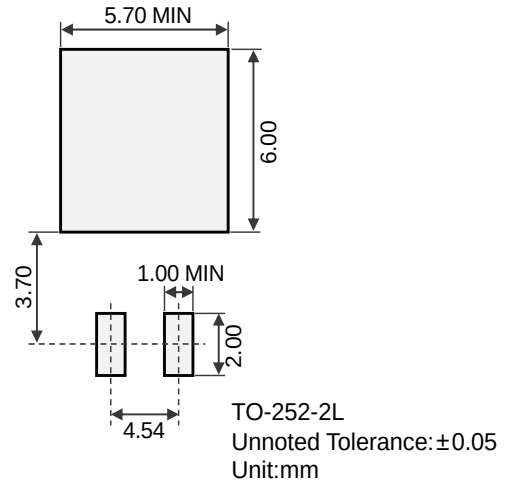


Package Outline Dimensions & Suggested Solder Pad Layout

Package Outline Dimensions



Suggested Solder Pad Layout



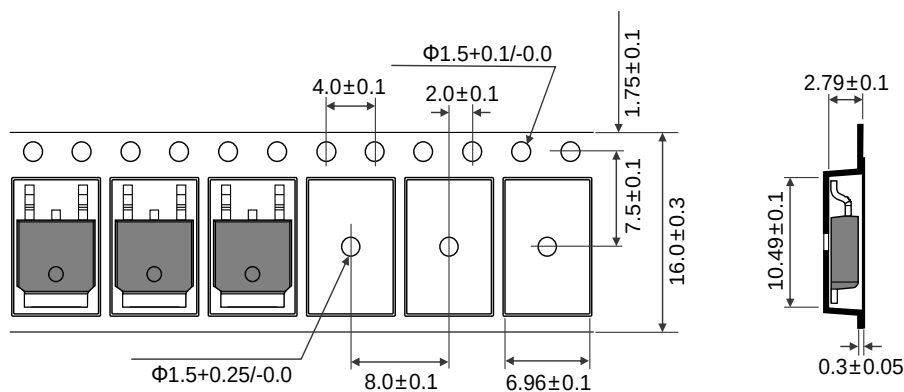
Marking Information



“MHCHXM”= Product Logo
“Marking Code”= The Following
“XXXX”= Date Code Marking

Marking Code	Part Number
C65N350S2	HXMC65N350S2

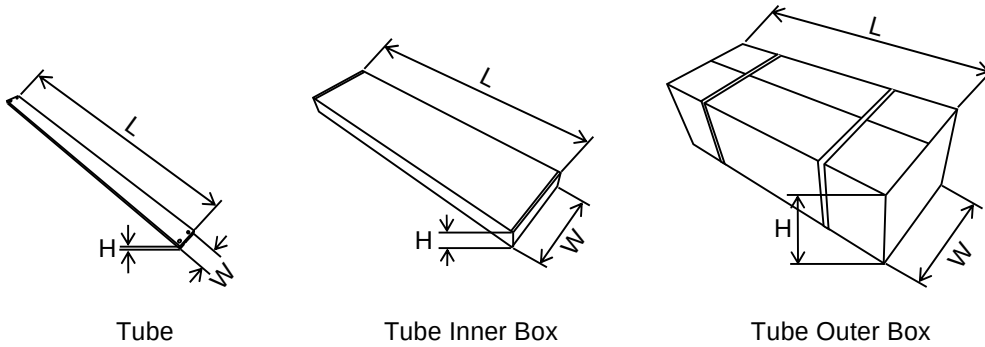
Reel Tape Dimensions (Dimensions in mm)



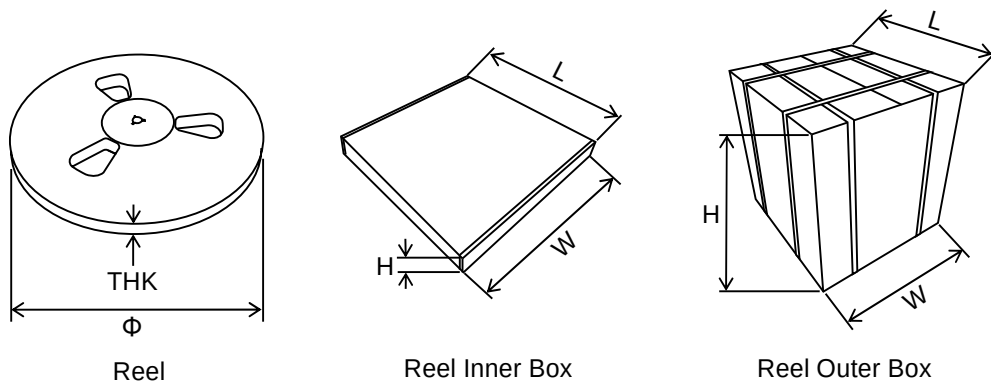
Packing Information

Packaging	Part Number	Quantity(pcs)	Size(mm)
Tube	Tube	80	L540×W20×H5
	Inner Box	4000	L570×W115×H55
	Outer Box	20000	L595×W320×H135
Reel	Reel	3000	Φ330×THK17
	Inner Box	3000	L350×W340×H25
	Outer Box	30000	L355×W300×H360

Packaging:Tube



Packaging:Reel



DISCLAIMER

1. Above specification may be changed without notice. MHCHXM will reserve authority on material change for above specification.
2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. MHCHXM assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
4. These specification sheets include materials protected under copyright of MHCHXM. Reproduction in any form is prohibited without the specific consent of MHCHXM.
5. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized MHCHXM sales agent for special application request.
6. Statements regarding the suitability of products for certain types of applications are based on MHCHXM's knowledge of typical requirements that are often placed on MHCHXM products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify MHCHXM's terms and conditions of purchase, including but not limited to the warranty expressed therein.
7. This publication supersedes & replaces all information previously supplied. For additional application information, please visit our website <http://www.jshxm.com> , or consult your nearest MHCHXM's sales office for further assistance.

